ELECTRICAL CHARACTERISTICS

Part Number	Working Voltage (Vw)	Breakdown Voltage (Vb)	Clamping Voltage (Vc)	Peak Current (lp)	Transient Energy (Et)	Capac	oical citance C)
	Volt	Volt	Volt	Amp	Joule	pF	
	<50 μ A	1mA(DC)	2.5A,8/20 μ s	8/20 μ s	10/1000 μ s	1KHz	1MHz
JMV0402S180T550	18.0	21.6~26.0	45	20	0.05	-	55

- Vw- The max. steady state DC operating voltage of which varistor could maintain also not exceeding 50uA leakage current.
- Vb- The Voltage acrossed the device measured at 1mA DC current.
- Vc- The peak voltage acrossed the varistor measured at a specified pulse current and waveform.
- Ip- The max.peak current applied with specified wavefoem without any possibility of device fail.
- Et- The max. energy which dissipated with the specified waveform without any possibility of device fail.
- C The device capacitance measured with zero volt bias, 1.0Vrms and 1KHz / 0.5 V rms and 1 MHz.

MLV Storage condition→Temperature: ≤30°C/ Humidity:≤60% RH(Moisture Sensitivity Levels: 2a)
MLV Preservation period→ 6 months

External Dimension

Chip Dimension	vn.		inch(mm)
Chip Dimensio)		
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Chip Size	L	W	Т	Α
0402	0.040±0.004	0.020±0.004	0.024max.	0.010±0.006
(1005)	(1.00±0.10)	(0.50±0.10)	(0.6max.)	(0.25±0.15)

